L Number	Hits	Search Text	DB	Time stamp
1	0	"L21" and ((light-emitting or light adj emitting) near12 thyristor) and (thyristor near12 (matrix or matrices or array))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03
2	70	((light-emitting or light adj emitting) near12 thyristor) and (thyristor near12 (matrix or matrices or array))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03 10:23
3	6	((light-emitting or light adj emitting) near12 thyristor) and (thyristor near12 (matrix or matrices or array)) and ((bond or bonding) adj pad)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03 11:58
4	92	array adj pitch and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03
5	17565	257/\$6.ccls. and array pitch same "micro.m"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03
6	17565	257/\$6.ccls. and (array pitch same "micro.m") and array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03
7	0	257/\$6.ccls. and (array adj pitch same "micro.m") and chip	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03 13:32
8	0	257/\$6.ccls. and (array adj pitch same "micro.m") and (die or chip)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/03
9	O	257/\$6.ccls. and (array adj pitch same "micro.m")	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/03
10	2	257/\$6.ccls. and (array adj pitch near6 value)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03 13:35
11	4	257/\$6.ccls. and (array adj pitch near6 micron)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03 13:37
12	0	257/\$6.ccls. and (array adj pitch near6 tolerance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/03
13	6257	((257/431).CCLS.) or ((257/432).CCLS.) or ((257/433).CCLS.) or ((257/290).CCLS.) or ((257/291).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/100).CCLS.) or ((257/100).CCLS.) or ((257/100).CCLS.) or ((257/100).CCLS.) or ((257/100).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/03 15:05

14	4	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
1.4	1	or ((257/431).CCLS.) or ((257/432).CCLS.)	USPAT; US-PGPUB;	14:25
Į į		or ((257/291).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	-1.50
	1	or ((257/293).CCLS.) or ((257/99).CCLS.)	DERWENT;	1
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM TDB	
		or ((257/102).CCLS.) or	_	
1		((257/103).CCLS.)) and (array or matrix)		1
		and (light-emitting or light adj		i
_	_	emitting) and (anode near2 line)		
15	7	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	14:27
		or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.)	EPO; JPO; DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM TDB	
		or ((257/102).CCLS.) or	13123	
		((257/103).CCLS.)) and (array or matrix)		
		and (light-emitting or light adj		
		emitting) and ((cathode or anode) near2	Ì	
		line)		
16	5	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
1		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	14:28
		or ((257/291).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	f
		or ((257/293).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.)	DERWENT;	
		or ((257/100).ccLs.) or ((257/101).ccLs.)	IBM_TDB	
		((257/103).CCLS.)) and (array or matrix)		
1		and (light-emitting or light adj	ĺ	
	ļ	emitting) and ((cathode or anode) near2		
		select\$3)		
17	0	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	14:31
]]]	or ((257/291).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	
{		or ((257/293).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.)	DERWENT; IBM TDB	
		or ((257/102).CCLS.) or	1011_100	
		((257/103).CCLS.)) and @pd<02012000		
18	6257	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	14:35
		or ((257/291).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	
		or ((257/293).CCLS.) or ((257/99).CCLS.)	DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.)	IBM_TDB	
		((257/102).CCLS.)) and @pd>02012000		
19	2925	((257/431).CCLS.) or ((257/432).CCLS.) or	USPAT	2002/05/03
		((257/433).CCLS.) or ((257/290).CCLS.) or		17:15
		((257/291).CCLS.) or ((257/292).CCLS.) or	1	
		((257/293).CCLS.) or ((257/99).CCLS.) or		
		((257/100).CCLS.) or ((257/101).CCLS.) or		
20	1150	((257/102).CCLS.) or ((257/103).CCLS.)	II.G.D.T.	2002/05/22
20	1156	((((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
[or ((257/433).CCLS.) or ((257/290).CCLS.) or ((257/291).CCLS.) or ((257/292).CCLS.)	US-PGPUB; EPO; JPO;	20:23
		or ((257/291).CCLS.) or ((257/292).CCLS.)	DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM TDB	
		or ((257/102).CCLS.) or		
		((257/103).CCLS.)) and @pd>02012000) and		
	į	array		
21	3	("5451977").PN.	USPAT;	2002/05/03
			US-PGPUB;	16:34
			EPO; JPO;	
]		DERWENT;	
24	0	("three near6 thyristor near6 array").PN.	IBM_TDB USPAT;	2002/05/03
47		(chiee heard chyristor heard array").PN.	US-PGPUB;	16:34
			EPO; JPO;	10.01
			DERWENT;	
			IBM TDB	
L				L

25	13	three near6 thyristor near6 array	USPAT;	2002/05/03
	15	three heard chyrracor heard array	US-PGPUB;	16:36
i			EPO; JPO;	
			DERWENT;	
26	_	hhara hamiaal manac hhamiahan aanc	IBM_TDB	2002/05/02
26	6	three-terminal near6 thyristor near6 array	USPAT;	2002/05/03 16:36
		allay	US-PGPUB; EPO; JPO;	10.30
]			DERWENT;	
			IBM_TDB	
27	86	(345/44).CCLS.	USPAT;	2002/05/03
			US-PGPUB;	17:24
			EPO; JPO; DERWENT;	
			IBM TDB	
29	326	(345/46).CCLS.	USPAT;	2002/05/03
			US-PGPUB;	17:25
			EPO; JPO;	
			DERWENT;	
28	100	(345/45).CCLS.	IBM_TDB USPAT;	2002/05/03
	100	(0.10, 10, 100.00)	US-PGPUB;	17:25
			EPO; JPO;	
			DERWENT;	
20	100	////257/421\ 0070 \ //257/420\ 5577	IBM_TDB	2002/05/22
30	120	(((((257/431).CCLS.) or ((257/432).CCLS.) or ((257/433).CCLS.) or ((257/290).CCLS.)	USPAT; US-PGPUB;	2002/05/03
		or ((257/291).CCLS.) or ((257/290).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	20:27
		or ((257/293).CCLS.) or ((257/99).CCLS.)	DERWENT;	
	İ	or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM_TDB	
)		or ((257/102).CCLS.) or		
		((257/103).CCLS.)) and @pd>02012000) and array) and shift adj register		
31	26	((((((257/431).CCLS.) or	USPAT;	2002/05/03
	20	((257/432).CCLS.) or ((257/433).CCLS.) or	US-PGPUB;	20:25
		((257/290).CCLS.) or ((257/291).CCLS.) or	EPO; JPO;	
	-	((257/292).CCLs.) or ((257/293).CCLs.) or	DERWENT;	
		((257/99).CCLS.) or ((257/100).CCLS.) or	IBM_TDB	
		((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and @pd>02012000) and		
		array) and shift adj register) and serial		
		and parallel		
32	14		USPAT;	2002/05/03
		((257/432).CCLS.) or ((257/433).CCLS.) or	US-PGPUB;	20:25
		((257/290).CCLS.) or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.) or	EPO; JPO; DERWENT;	
		((257/99).CCLS.) or ((257/100).CCLS.) or	IBM TDB	
		((257/101).CCLS.) or ((257/102).CCLS.) or		
		((257/103).CCLS.)) and @pd>02012000) and		
		array) and shift adj register) and serial		
33	14	same parallel (((((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
	1-3	or ((257/431).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	20:28
		or ((257/291).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	· =
		or ((257/293).CCLS.) or ((257/99).CCLS.)	DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM_TDB	
		or ((257/102).CCLS.) or ((257/103).CCLS.)) and @pd>02012000) and		
		array) and (shift adj register same		
		serial same parallel)		
34	7	(((((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/03
		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	20:28
		or ((257/291).CCLS.) or ((257/292).CCLS.)	EPO; JPO;	
		or ((257/293).CCLS.) or ((257/99).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.)	DERWENT; IBM TDB	
		or ((257/100).ccLs.) or ((257/101).ccLs.)	1011_100	
		((257/103).CCLS.)) and @pd>02012000) and		
		array) and (shift adj register same		
<u></u>		serial same parallel same array)	L	<u> </u>

		L: 02510117000A A 1: 1	Tropam.	1 2002 (05 (02
35	0	jp-03519117280\$-\$.did.	USPAT;	2002/05/03
			US-PGPUB;	21:26
			EPO; JPO;	
		•	DERWENT;	
36	31	kamei.in. and yojiro.in.	IBM_TDB USPAT;	2002/05/03
30	31	kamer.m. and yojiro.m.	US-PGPUB;	21:26
			EPO; JPO;	21:26
}			DERWENT;	ĺ
			IBM TDB	
37	4	kamei.in. and yojiro.in. and light adj	USPAT;	2002/05/03
3,		emitting.ti.	US-PGPUB;	21:26
	1	emicing.ci.	EPO; JPO;	21.20
			DERWENT;	
			IBM TDB	
38	3	("4394653").PN.	USPAT;	2002/05/03
		(1031003) 11111	US-PGPUB;	21:37
			EPO; JPO;	21.3,
			DERWENT;	
	j		IBM TDB	
39	3	("5763909").PN.	USPAT;	2002/05/03
		(- , - ,	US-PGPUB;	21:37
	1		EPO; JPO;	
[DERWENT;	
			IBM TDB	
-	93		USPAT;	2002/05/02
		emitting).ti,ab. and thyristor.ti,ab. and	US-PGPUB;	17:02
	İ	(array or matrix).ti,ab.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	5	(light-emitting or light adj	USPAT;	2002/05/02
		emitting).ti,ab. and thyristor.ti,ab. and	US-PGPUB;	17:18
	į	(array or matrix).ti,ab. and 257/\$6.ccls.	EPO; JPO;	1
			DERWENT;	
ļ			IBM_TDB	
-	0	("jp-3194978\$-\$.did.").PN.	USPAT;	2002/05/02
			US-PGPUB;	17:18
			EPO; JPO;	1
	1		DERWENT;	
	_		IBM_TDB	
-	2	jp-03194978\$-\$.did.	USPAT;	2002/05/02
			US-PGPUB;	17:49
	į		EPO; JPO;	
			DERWENT;	
	\		IBM_TDB	2222 (25 (22
-	2	jp-09150543\$-\$.did.	USPAT;	2002/05/02
			US-PGPUB;	17:24
			EPO; JPO;	
	ļ		DERWENT;	
_	2	jp-09216416\$-\$.did.	USPAT;	2002/05/02
	2	JE OSETOTION AVOIDA.	US-PGPUB;	17:26
			EPO; JPO;	-/
			DERWENT;	
			IBM TDB	
-	0	jp-0283792\$-\$.did.	USPAT;	2002/05/02
			US-PGPUB;	17:27
1			EPO; JPO;	. –
			DERWENT;	
			IBM TDB	
-	2	jp-09283792\$-\$.did.	USPAT;	2002/05/02
1			US-PGPUB;	17:27
			EPO; JPO;	
	1		DERWENT;	
1			IBM_TDB	
-	492	(257/431).CCLS.	USPAT;	2002/05/02
			US-PGPUB	17:50
-	488	(257/432).CCLS.	USPAT;	2002/05/02
			US-PGPUB	17:50
-	299	(257/433).CCLS.	USPAT;	2002/05/02
			US-PGPUB	17:50

_	226	(257/290).CCLS.	USPAT;	2002/05/02
	260	/257/201\ CCT C	US-PGPUB	17:50
_	260	(257/291).CCLS.	USPAT; US-PGPUB	2002/05/02
-	278	(257/292).CCLS.	USPAT;	2002/05/02
_	53	(257/293).CCLS.	US-PGPUB USPAT;	17:50 2002/05/02
			US-PGPUB	17:50
-	497	(257/99).CCLS.	USPAT;	2002/05/02
_	140	(257/100).CCLS.	US-PGPUB USPAT;	17:50 2002/05/02
			US-PGPUB	17:50
_	180	(257/101).CCLS.	USPAT; US-PGPUB	2002/05/02
_	214	(257/102).CCLS.	USPAT;	2002/05/02
	701	(257/103).CCLS.	US-PGPUB USPAT;	17:51 2002/05/02
	/01	(237/103):0013.	US-PGPUB	17:51
-	2	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/02
		or ((257/433).CCLS.) or ((257/290).CCLS.) or ((257/291).CCLS.) or ((257/292).CCLS.)	US-PGPUB; EPO; JPO;	18:45
		or ((257/293).CCLS.) or ((257/99).CCLS.)	DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or	IBM_TDB	
		((257/103).CCLS.)) and (((light-emitting		
		or light adj emitting) near12 thyristor)		
_	1	nearl2 (matrix or matrices or array)) ((((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/02
		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	17:55
		or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.)	EPO; JPO; DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM TDB	
		or ((257/102).CCLS.) or	_	
		((257/103).CCLS.)) and (((light-emitting or light adj emitting) near12 thyristor)		
		near12 (matrix or matrices or array)))		
_	11	and (chip or die) (US-4754175-\$ or US-6180960-\$).did. or	USPAT;	2002/05/02
		(JP-03194978-\$ or JP-09150543-\$ or	JPO;	18:11
		JP-09216416-\$ or JP-09283792-\$).did. or (JP-03194978-\$ or JP-09150543-\$ or	DERWENT	
		EP-335553-\$ or US-6180960-\$).did.		
-	0	((US-4754175-\$ or US-6180960-\$).did. or	USPAT;	2002/05/02
		(JP-03194978-\$ or JP-09150543-\$ or JP-09216416-\$ or JP-09283792-\$).did. or	US-PGPUB; EPO; JPO;	18:12
		(JP-03194978-\$ or JP-09150543-\$ or	DERWENT;	
		EP-335553-\$ or US-6180960-\$).did.) and bond\$3 adj pad	IBM_TDB	
-	2	(((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/02
		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	18:51
		or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.) or ((257/99).CCLS.)	EPO; JPO; DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM_TDB	
		or ((257/102).CCLS.) or ((257/103).CCLS.)) and ((light-emitting		
		or light adj emitting) near12 thyristor)		
		and (thyristor near12 (matrix or matrices		
_	5	or array)) ((((257/431).CCLS.) or ((257/432).CCLS.)	USPAT;	2002/05/02
,		or ((257/433).CCLS.) or ((257/290).CCLS.)	US-PGPUB;	18:57
		or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.)	EPO; JPO; DERWENT;	
		or ((257/100).CCLS.) or ((257/101).CCLS.)	IBM_TDB	
		or ((257/102).CCLS.) or		
		((257/103).CCLS.)) and ((light-emitting or light adj emitting) near12 (array or		
L		matrix or matrices))) and thyristor		

	· · · · · · · · · · · · · · · · · · ·			
_	0	(((((257/431).CCLS.) or ((257/432).CCLS.) or ((257/433).CCLS.) or ((257/290).CCLS.) or ((257/291).CCLS.) or ((257/291).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and ((light-emitting or light adj emitting) nearl2 (array or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/02 18:56
_	5	matrix or matrices))) and thyristor) and bonding adj pad (((((257/431).CCLS.) or ((257/432).CCLS.) or ((257/433).CCLS.) or ((257/291).CCLS.) or ((257/291).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/100).CCLS.) or ((257/100).CCLS.) or ((257/103).CCLS.) or ((257/103).CCLS.) or ((257/103).CCLS.)) and ((light-emitting	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/02 18:57
-	5	or light adj emitting) near12 (array or matrix or matrices))) and thyristor) and thyristor (((257/431).CCLS.) or ((257/432).CCLS.) or ((257/291).CCLS.) or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/100).CCLS.) or ((257/101).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/02 18:57
_	33	or ((257/102).CCLS.) or ((257/103).CCLS.) or ((257/103).CCLS.)) and ((light-emitting or light adj emitting) nearl2 (array or matrix or matrices))) and thyristor (((257/431).CCLS.) or ((257/432).CCLS.) or ((257/291).CCLS.) or ((257/291).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/02 19:37
	0	or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and ((light-emitting or light adj emitting) near12 (array or matrix or matrices))) and bonding adj pad (((((257/431).CCLS.) or ((257/432).CCLS.) or ((257/433).CCLS.) or ((257/291).CCLS.) or ((257/291).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/02 19:37
-	218	or ((257/100).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and ((light-emitting or light adj emitting) near12 (array or matrix or matrices))) and bonding adj pad) and thyristor (((257/431).CCLS.) or ((257/432).CCLS.) or ((257/433).CCLS.)	IBM_TDB USPAT; US-PGPUB;	2002/05/02 19:56
	26	or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.) or ((257/293).CCLS.) or ((257/101).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.) or ((257/103).CCLS.)) and ((light-emitting or light adj emitting) near12 (array or matrix or matrices)) (((257/431).CCLS.) or ((257/432).CCLS.)	EPO; JPO; DERWENT; IBM_TDB	2002/05/02
	26	or ((257/433).CCLS.) or ((257/290).CCLS.) or ((257/291).CCLS.) or ((257/292).CCLS.) or ((257/293).CCLS.) or ((257/100).CCLS.) or ((257/100).CCLS.) or ((257/102).CCLS.) or ((257/103).CCLS.)) and (gate-selecting or gate adj selecting or gate near10	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	20:03
-	4798	select\$3) adj2 line (gate-selecting or gate adj selecting or gate near10 select\$3) adj2 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/02 20:04

Gate-selecting or gate adj selecting or gate nearlo selects] adj2 line and thyristor and bond adj pad USPAT; USPAT					
thyristor and bond adj pad Comparison of the part o	-	0	(gate-selecting or gate adj selecting or	USPAT;	1
DERMENT: IBM TOB USPAT:					20:05
1			thyristor and bond adj pad	EPO; JPO;	1
- 0 (gate-selecting or gate adj selecting or gate near10 select\$3 adj2 line and bond adj pad and (light-emitting or light adj emitting)				1	
gate near10 selects3) adj2 line and bond adj pad and (light-emitting or light adj emitting) 30 (gate-selecting or gate adj selecting or gate near10 selects3) adj2 line and thyristor 30 (gate-selecting or gate adj selecting or gate near10 selects3) adj2 line and bond adj pad 30 pad and 257/\$6.ccls. 30 pad 2002/05/02 p				IBM_TDB	
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-	1	"5753941".PN.	USPAT	2002/05/02
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_	15	(matrix or array) same (light-emitting or	USPAT;	2002/05/02
	1	light adj emitting or thyristor) same	US-PGPUB;	22:18
		bond adj pad and 257/\$6.ccls.	EPO; JPO;	
			DERWENT;	
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-	152		USPAT;	2002/05/02
		thyristor) same (bond or bonding) adj pad	US-PGPUB;	22:19
		and 257/\$6.ccls.	EPO; JPO;	
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		thyristor) same (plurality near3 (bond or	US-PGPUB;	22:20
	1	bonding) adj pad) and 257/\$6.ccls.	EPO; JPO;	1
			DERWENT;	
	<u> </u>		IBM_TDB	